

**SUBJECT: ELECTRONICS/TELECOMMUNICATION ENGINEERING: PAPER –I**  
**SET-A**

Time: 3 hours

Full Marks: 200

Note: Answer Question No. 1 and any four from the rest. All questions carry equal marks.

Q1. Answer any ten (10)

10 x 4 = 40

- (a) What is reverse saturation current in reference to a p-n junction diode?
- (b) What are intrinsic and extrinsic semiconductors?
- (c) What is depletion region in p-n junction?
- (d) If vector  $\vec{A} = 5\hat{a}_x + 6\hat{a}_y + 3\hat{a}_z$  and vector  $\vec{B} = \hat{a}_x + 4\hat{a}_y$ , Find a unit vector along  $\vec{A} + 2\vec{B}$
- (e) State maximum power transfer theorem.
- (f) Define Poynting vector.
- (g) What are the active and passive type instruments?
- (h) A series RLC circuit with  $R=3K\Omega$ ,  $L=10H$ ,  $C=200\mu F$ , has a constant voltage source,  $V=50V$ , applied at time  $t=0$ . Obtain the transient current if the capacitor has no initial charge.
- (i) Define dipole and dipole moment.
- (j) What are variables? How variables are declared in C language?
- (k) Define the terms: span and tolerance used in instrumentation.
- (l) What is the physical definition of curl of a vector field?
- (m) Find the divergence of the vector  $\vec{A} = yz\hat{a}_x + 4xy\hat{a}_y + y\hat{a}_z$  at  $(1, -2, 3)$

Q2. Answer any eight (8)

8 x 5 = 40

- (a) The reverse saturation current at 300K of a p-n junction Ge diode is  $5\mu A$ . Find the voltage to be applied across the junction to obtain a forward current of 50mA.
- (b) How avalanche breakdown occurs in p-n junction diode?
- (c) What is a rectifier circuit? How full wave rectification can be achieved?
- (d) Define a two port network. Calculate the equivalent z-parameters of two series connected two-port networks in terms of the individual z-parameters of each network.
- (e) State and explain the laws of thermocouple.
- (f) What is an isolation amplifier?
- (g) Find the average and *rms* value of a half wave rectified signal.
- (h) Find form factor and crest factor of a voltage signal  $v=200 \sin 314t$ :
- (i) A strain gauge is bound to a short column which is then loaded in compression. The resistance of the strain gauge is  $240\Omega$  before loading and  $230\Omega$  while load is

applied. The Gauge Factor of the strain gauge is 2.15. The column has a cross section of 20 mm x 15 mm. Young's Modulus of the material is 70 GNm<sup>-2</sup>. Determine the load carried by the column.

- (j) Explain the construction and working principle of linear variable differential transducer.

Q3. Answer any five (5)

5 x 8 = 40

- Explain the *Volt-Ampere (V-I)* characteristics of a p-n junction in forward and reverse bias condition.
- Distinguish between clipping and clamping circuits.
- What is an instrumentation amplifier?
- The voltage applied to a circuit is  $e = 100 \sin(\omega t + 30^\circ) V$  and the current flowing in the circuit is  $i = 15 \sin(\omega t + 60^\circ) A$ . Determine impedance, resistance, reactance and power factor of the circuit.
- What are frequency division and time division multiplexing?
- Calculate the voltage drop across and current through the load resistance ( $R_L$ ) for the circuit shown in figure 1. The Silicon p-n junction diode has a cut-in voltage of 0.7V.

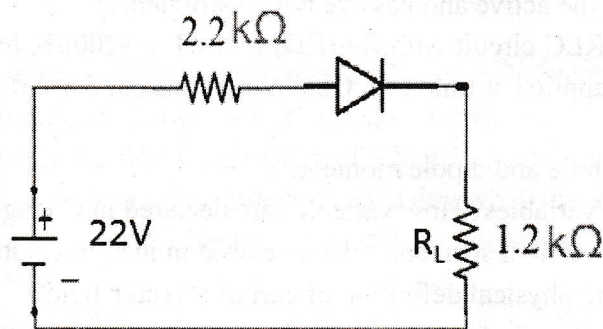


Figure 1

- (g) State Norton's theorem. Write the steps used to Nortonize a circuit.

Q4. Answer any four (4)

4 x 10 = 40

- Draw potential energy band diagram of an unbiased p-n junction diode. What changes will occur in the band diagram when it is positively and negatively biased?
- What is ripple factor? Explain how the ripples in a full wave rectified signal can be minimized using capacitive filters?
- Show that a source free series RLC circuit in under-damped condition produces oscillatory natural response.
- Write the four Maxwell's equations and give their physical interpretation.
- Design an algorithm and the corresponding flowchart for adding the test scores as given below:  
26, 49, 98, 87, 62, 75

Q5. Answer any two (2)

2 x 20 = 40

- (a) A half wave rectifier uses a diode with a forward resistance of  $50\Omega$ . If the input ac voltage is 20 V (rms) and the load resistance is  $1.2\text{ k}\Omega$ , determine the (i) dc load current (ii) ac load current (iii) peak inverse voltage (iv) load output voltage (v) dc output power and (vi) conversion efficiency.
- (b) (i) Determine the equivalent resistance between terminal A and B in the circuit shown in figure 2. Also determine the potential drop across  $2\Omega$  resistor in the network.  
(ii) State Thevenin's theorem. Obtain the Thevenin equivalent circuit for the network shown in figure 3.

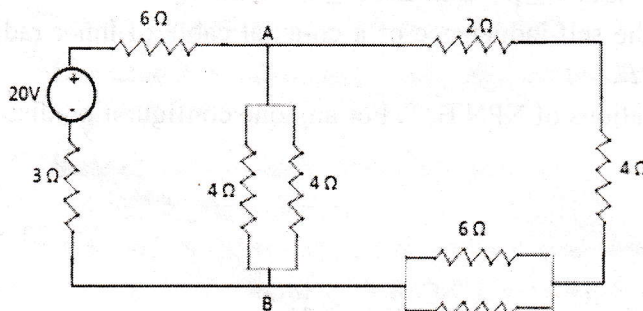


Figure 2

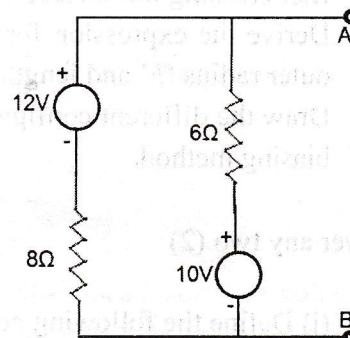


Figure 3

- (c) Find the equivalent value of the input resistance of the circuit shown in figure 4 using star-delta conversion method.

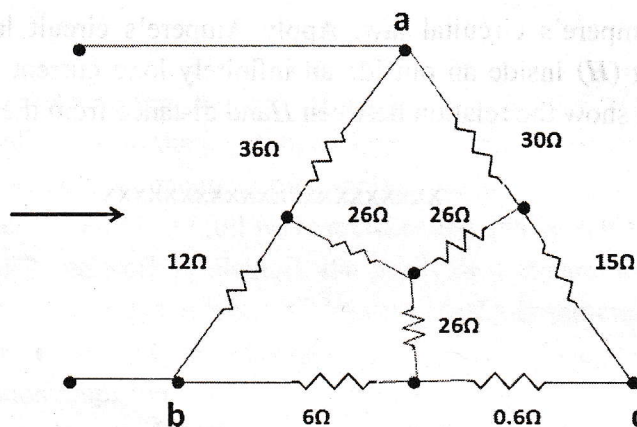


Figure 4

Q6. Answer any four (4)

4 x 10 = 40

- (a) Define an algorithm. State the benefits of using an algorithm.
- (b) What are the basic symbols used in a flow chart and what are their functions?
- (c) State Biot-Savart's law. Find the magnitude and direction of magnetic field intensity ( $H$ ) at point  $(-4, 4, 0)$  due to a semi-infinite current filament carrying a current of 3A.
- (d) Given the magnetic vector potential  $A = -\frac{\rho^2}{4} a_z$  wb/m, calculate the total magnetic flux crossing the surface  $\phi = \pi/2$ ,  $1 \leq \rho < 2$  m and  $0 \leq z < 5$  m.
- (e) Derive the expression for the self-inductance of a co-axial cable of inner radius ' $a$ ', outer radius ' $b$ ' and length ' $l$ '.
- (f) Draw the different configurations of NPN BJT. For any one configuration discuss one biasing method.

Q7. Answer any two (2)

2 x 20 = 40

- (a)
  - (i) Define the following performance characteristics of instrument: accuracy, precision, resolution, sensitivity, and hysteresis.
  - (ii) A thermocouple has a linear sensitivity of  $30 \mu\text{V}/^\circ\text{C}$ , calibrated at a cold junction temperature of  $0^\circ\text{C}$ . It is used to measure an unknown temperature with the cold junction temperature of  $30^\circ\text{C}$ . Find the actual hot junction temperature if the emf generated is 3.0mV.
- (b) Explain the operation of successive approximation type analog to digital converter. Define the conversion time and quantization error of an analog to digital converter (ADC).
- (c) State Ampere's circuital law. Apply Ampere's circuit law to find magnetic field intensity ( $H$ ) inside and outside an infinitely long current carrying conductor. Plot a graph to show the relation between  $H$  and distance from the center of the conductor.

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